Low On-Resistance Wideband/Video Quad with Individual Control

Features:

- High-performance, low-cost solution to switch between video sources
- Wide bandwidth: 250 MHz
- Low On-Resistance: 3Ω
- Low crosstalk at 10 MHz: –58 dB
- Ultra-low quiescent power (0.1µA typical)
- Single supply operation: +5.0V
- Fast switching: 10ns
- High-current output: 100mA
- Functionally equivalent to QS4A101
- Packaging (Pb-free & Green available):
  – 16-pin 150-mil wide plastic QSOP (Q)
  – 16-pin 150-mil wide plastic SOIC (W)

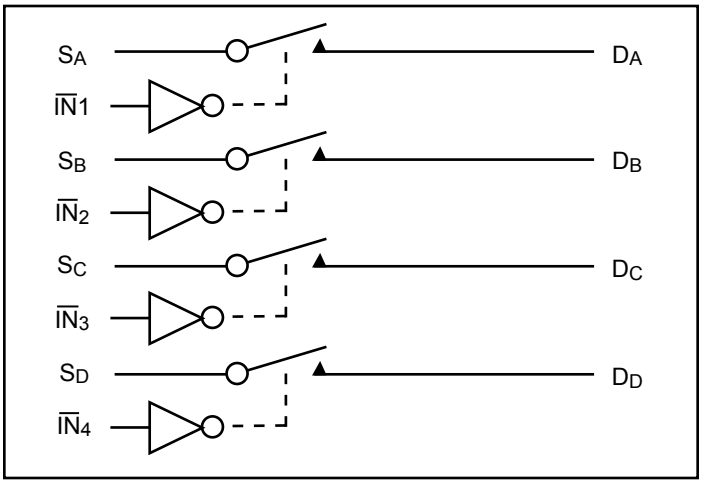
Description:

Pericom Semiconductor's PI5V332 is a true bidirectional Quad Video Switch that is recommended for RGB, S-Video, or composite video switching applications. The individual controls allow for video, Hsync, or Vsync enable or disable. The switch can be driven from a current output RAMDAC or voltage output composite video source.

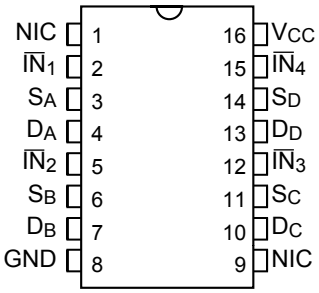
Low On-Resistance and wide bandwidth make it ideal for video and other applications. Also this device has exceptionally high current capability which is far greater than most analog switches offered today. A single 5V supply is all that is required for operation.

The PI5V332 offers a high-performance, low-cost solution to switch between video sources.

Block Diagram



Pin Configuration



Truth Table

$\overline{IN}_1$	$\overline{IN}_2$	$\overline{IN}_3$	$\overline{IN}_4$	Function
0	X	X	X	S_A - D_A
X	0	X	X	S_B - D_B
X	X	0	X	S_C - D_C
X	X	X	0	S_D - D_D
1	1	1	1	Disconnect

Pin Description

Pin Name	Description
S_X	Analog Video I/O (Usually Inputs)
$\overline{IN}_X$	Select Inputs
DA_X	Analog Video I/O (Usually Outputs)
GND	Ground
V_{CC}	Power Supply

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V_{CC} Only)	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current	120mA
Power Dissipation	0.5W

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 5V ±5%)

Parameters	Description	Test Conditions[1]	Min.	Typ[2]	Max.	Units
V_{ANALOG}	Analog Signal Range		0	—	2.0	V
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	—	—	
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	–0.5	—	0.8	
I_{IH}	Input HIGH Current	V_{CC} = Max., V_{IN} = V_{CC}	—	—	±1	µA
I_{IL}	Input LOW Current	V_{CC} = Max., V_{IN} = GND	—	—	±1	
I_O	Analog Output Leakage Current	0 ≤ S_1, S_2 or D ≤ V_{CC}, Switch Off	—	—	±1	
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = –18 mA	—	–0.7	–1.2	V
I_{OS}	Short Circuit Current[3]	S_1, S_2, D = 0V V_{CC}	100	—	—	mA
V_H	Input Hysteresis at Control Pins		—	150	—	mV
R_{ON}	Switch On-Resistance[4]	V_{CC} = Min., V_{OUT} = 0.975V R_L = 75Ω, I_{ON} = 13mA	—	3	7	Ω
		V_{CC} = Min., V_{OUT} = 1.95V R_L = 75Ω, I_{ON} = 26mA	—	7	10	

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, T_A = 25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. Measured by the voltage drop between S_1, S_2, and D I/O pins at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the S_1, S_2, and D I/O pins. V_{OUT} is the voltage across R_L.

Dynamic Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 5V ±5%)

Parameter	Description	Test Conditions	Min.	Typ.	Max.	Unit
t_{ON}	Turn On Time	R_L = 75Ω, C_L = 20pF, see Fig. 2	—	2.5	5	ns
t_{OFF}	Turn Off Time	R_L = 75Ω, C_L = 20pF, see Fig. 2	—	1.1	5	
B_W(1)	–3 dB Bandwidth	R_L = 150Ω, see Fig. 3	250	—	—	MHz
X_{TALK}	Crosstalk	R_{IN} = 10Ω; R_L = 150Ω, 10 MHz, see Fig. 3	—	–58	—	dB
D_G	Differential Gain	R_L = 150Ω, f = 3.58 MHz, see Fig. 1	—	0.64	—	%
D_P	Differential Phase	R_L = 150Ω, f = 3.58 MHz, see Fig. 1	—	0.27	—	Deg.
C_{IN}(1)	Input/Enable Capacitance	V_{IN} = 0V, f = 1 MHz	—	—	6	pF
C_{OFF}(1)	Capacitance, Switch Off	V_{IN} = 0V, f = 1 MHz	—	—	6	
C_{ON}(1)	Capacitance, Switch On	V_{IN} = 0V, f = 1 MHz	—	—	20	
O_{IRR}	Off Isolation	R_L = 150Ω, 10 MHz, see Fig. 3	—	–38	—	dB

Notes:
1. This parameter is determined by device characterization but is not production tested.

Power Supply Characteristics

Parameters	Description	Test Conditions(1)		Min.	Typ(2)	Max.	Units
I_{CC}	Quiescent Power Supply Current	V_{CC} = Max.	IN = GND or V_{CC}	—	0.1	3.0	µA
ΔI_{CC}	Supply Current per Input @ TTL HIGH	V_{CC} = Max.	IN = 3.4V(3)	—	—	2.5	mA
I_{CCD}	Supply Current per Input per MHz(4)	V_{CC} = Max., S_1, S_2, and D Pins Open $\overline{EN}$ = GND Control Input Toggling 50% Duty Cycle		—	—	0.25	mA/ MHz

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4V, control inputs only); S_1, S_2, and D pins do not contribute to I_{CC}.
4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The S_1, S_2, and D I/O pins generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

Definitions

Symbol	Description
R_{ON}	Resistance between source and drain with switch in the ON state.
I_O	Output leakage current measured at S_1, S_2, and D with the switch OFF.
V_{IN}	Digital voltage at the IN pin that selects between S_1 and S_2 analog inputs.
V_{EN}	A voltage that ENABLES the chip.
C_{IN}	Capacitance at the digital inputs.
C_{OFF}	Capacitance at analog I/O (S_1, S_2, D) with switch OFF.
C_{ON}	Capacitance at analog I/O (S_1, S_2, D) with switch ON.
V_{IH}	Minimum input voltage for logic HIGH.
V_{IL}	Minimum input voltage for logic LOW.
I_{IH} (I_{IL})	Input current of the digital input.
I_{OS}	Minimum short circuit current for S1, S2 and D.
t_{ON}	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned ON. The peak analog voltage is 0.714V.
t_{OFF}	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned OFF. The peak analog voltage is 0.714V.
B_W	Frequency response of the switch in the ON state measured at 3dB down.
X_{TALK}	Is an unwanted signal coupled from channel to channel. Measured in –dB. X_{TALK} = 20 LOG V_{OUT}/V_{IN}. This is non-adjacent crosstalk.
D_G	Differential gain is the difference measurement between two bias levels, for instance analog input signals of 0V to 0.714V.
D_P	Differential phase is the difference measurement between two bias levels, for instance analog input signals of 0V to 0.714V.
O_{IRR}	Off isolation is the resistance (measured in –dB) between the input and output with the switch off (NO).

Test Circuits

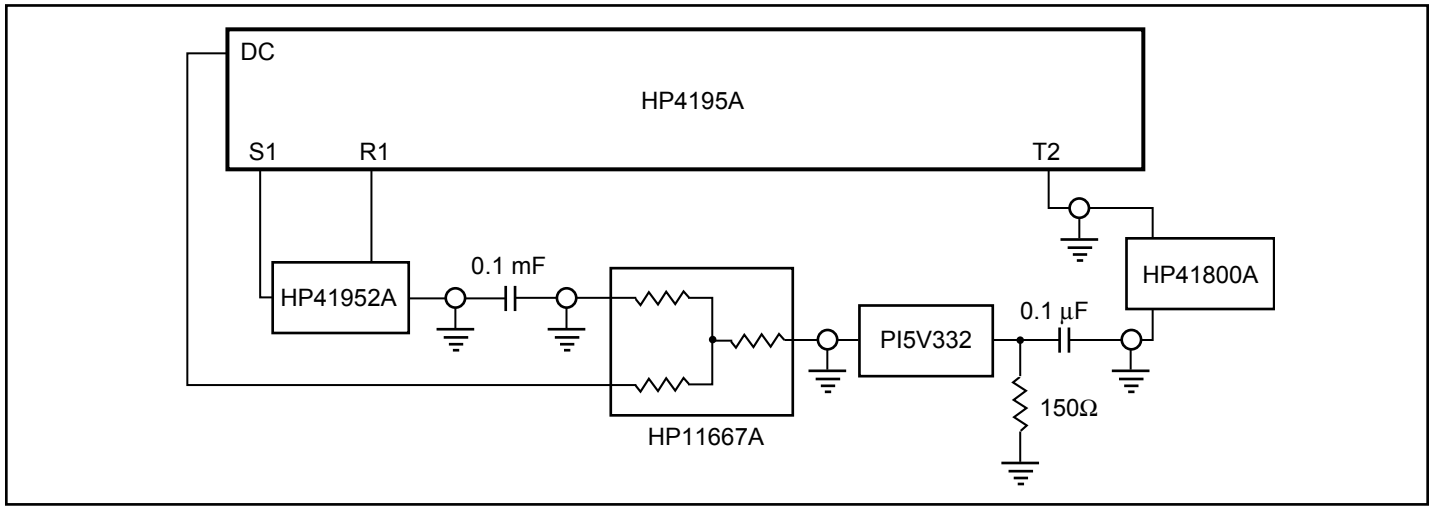


Figure 1. Differential Gain/Phase

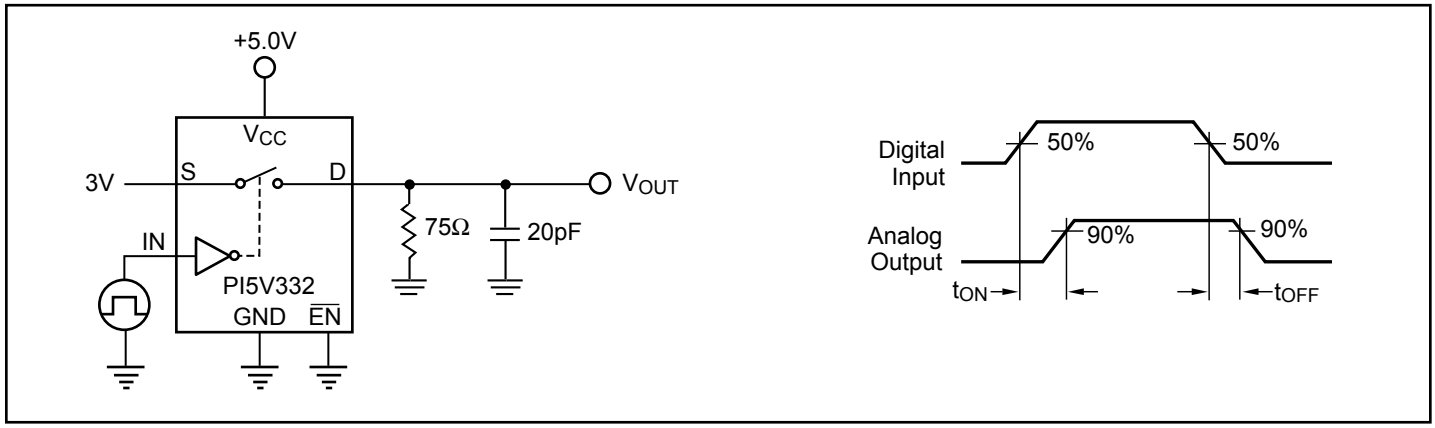


Figure 2. Switching Time

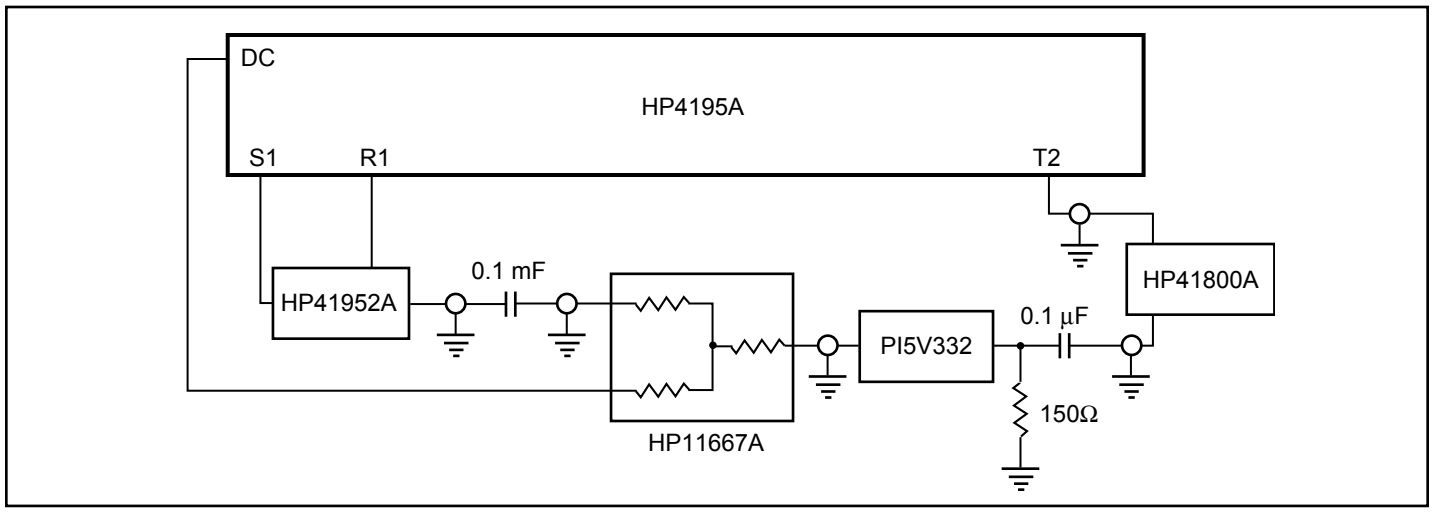
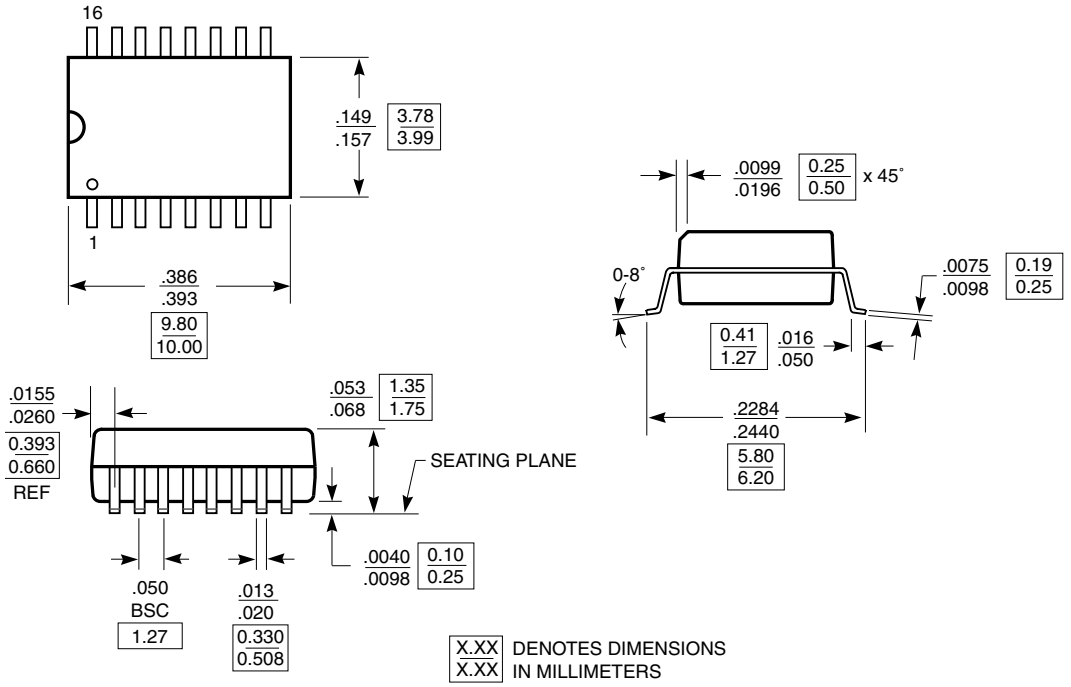
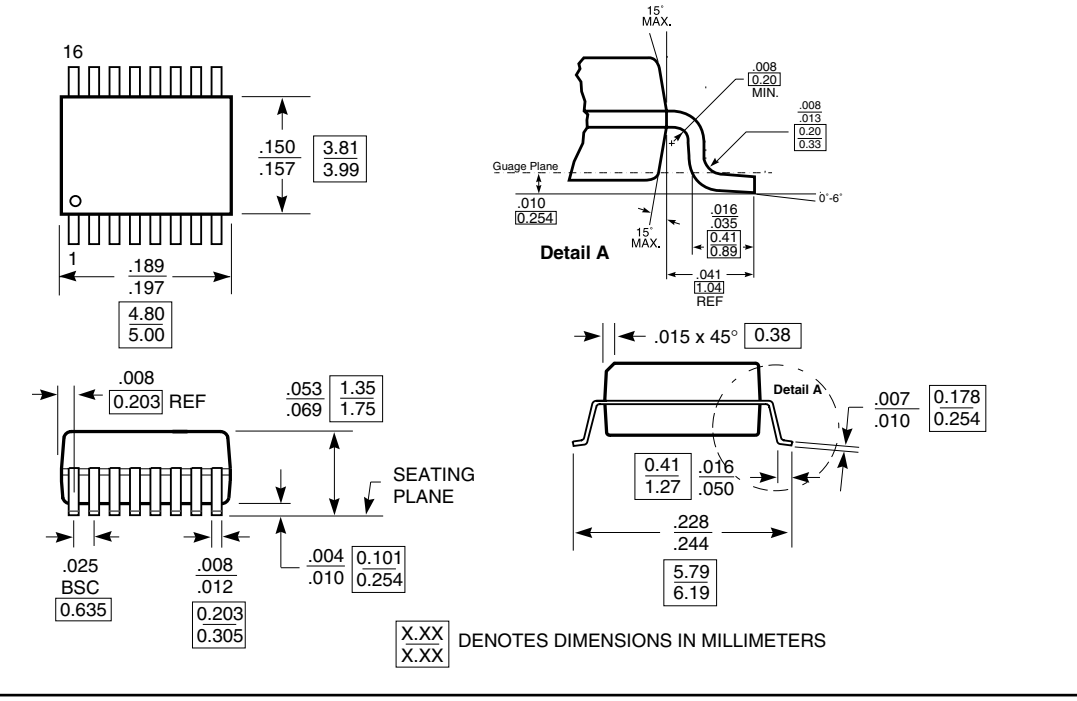


Figure 3. Gain/Phase, Crosstalk, Off-Isolation

Packaging Mechanical: 16-pin SOIC (W)



Packaging Mechanical: 16-pin QSOP (Q)



Ordering Information

Ordering Code	Package Code	Package Description
PI5V332W	W	16-pin SOIC
PI5V332WE	W	Pb-free & Green, 16-pin SOIC
PI5V332Q	Q	16-pin QSOP
PI5V332QE	Q	Pb-free & Green, 16-pin QSOP

Notes:
1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/